

3-Channel Constant Current Driver

Product Description

The SCT2001 is designed to drive multiple LEDs in series from a high input voltage rail. The SCT2001 contains three output channels which are regulated to sink constant current for driving LEDs of large range V_F variations.

In the field of LEDs driving applications, users can simply adjust the output current from 10 mA to 45 mA through an external resistor R_{ADJ} to control the light intensity of LEDs. The SCT2001 guarantees to endure maximum DC 24V at each output port.

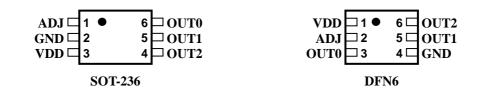
Features

• Three constant-current outputs rate at 24V

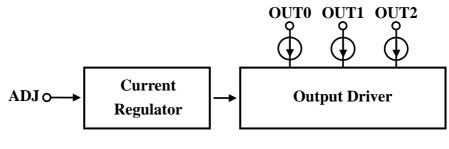
Technology

- Constant current range:10 45mA
- Wide operating supply input: 5 15V
- ±2%(typ) current matching between outputs
- ±4%(typ) current matching between ICs
- Smart dimming control via ADJ pin
- Low drop-out output 0.3V@20mA
- Excellent current regulation to load, supply voltage and temperature
- All output current are adjusted through one external resistor
- Hysteresis input for external resistor
- Built-in power on reset and thermal protection function
- Package: Small 2mmx2mm DFN and SOT-236
- Applications: Mini light bar, LED backlight, LED lamp

Pin Configurations



Block Diagram



SCT2001

Terminal Description

For SOT-236

Pin No.	Pin Name	Function
1	ADJ	Input terminal used to set up all output current
2	GND	Ground terminal
3	VDD	Supply voltage terminal
4	OUT2	Output terminal 2
5	OUT1	Output terminal 1
6	OUT0	Output terminal 0

For DFN6

Pin No.	Pin Name	Function			
1	VDD	Supply voltage terminal			
2	ADJ	Input terminal used to set up all output current			
3	OUT0	Output terminal 0			
4	GND	Ground terminal			
5	OUT1	Output terminal 1			
6	OUT2	Output terminal 2			

Ordering information

Part	Marking	Package	Unit per reel(pcs)
SCT2001AS1G	2001	Green SOT-236	3000
SCT2001ADNG	01A	Green DFN6	3000

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Maximum Ratings ($T_A = 25^{\circ}C$)

Characterist	Symbol	Rating	Unit	
Supply voltage		V_{DD}	17	V
Input voltage		V_{ADJ}	$-0.4 \sim V_{DD} + 0.4$	V
Output current		I _{OUT}	60	mA
Output voltage	V _{OUT}	24	V	
Total GND terminals curr	I _{GND}	200	mA	
Power dissipation	SOT-236	PD	1.09	W
Power dissipation	DFN6	ГD	2.24	vv
Thermal resistance	SOT-236	D	115	°C /W
DFN6		R _{TH(j-a)}	55.77	0700
Operating temperature	T _{OPR}	-40~+85	°C	
Storage temperature		T _{STG}	-55~+150	°C

Recommended Operating Conditions (T_A= -40 to 85°C unless otherwise noted)

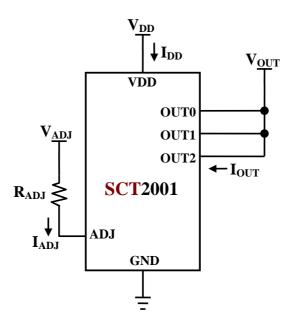
Characteristic	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply voltage	V_{DD}	-	5	-	15	V
	V	Output OFF	-	-	24	V
Output voltage	V _{OUT}	Output ON	-	1	4	V
Output current	I _{OUT}	DC test circuit	10	-	45	mA
Dimming pulse width	t _{vv}	V _{DD} =5-15V	2	-	-	us
Dimming rise time	t _R	V _{DD} =5-15V	-	-	1	us
Dimming fall time	t _F	V _{DD} =5-15V	-	-	1	us

Electrical Characteristics (V _{DD} =5-15V, V _{ADJ} =5V, T _A =	=25°C unless otherwise specified)
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Characteristic	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply current	I _{DD}	V _{DD} =5-15V	-	0.8	1	mA
ADJ input voltage	V _{IH}	-	2.5	-	-	V
ADJ input voltage	V _{IL}	-	-	-	20	mV
ADJ input current	I _{ADJ}	R _{ADJ} =4.8K	-	1	-	mA
Output leakage	I _{OL}	V _{OUT} =24V, V _{ADJ} =0V	-	-	0.5	uA
Output current	I _{OUT}	R _{ADJ} =4.8K	-	20	-	mA
Current channel skew [*]	dl _{OUT1}	V _{OUT} =1V,R _{ADJ} =4.8K	-	±2	±3	%
Current chip skew	dl _{OUT2}	V _{OUT} =1V,R _{ADJ} =4.8K	-	±4	±6	%
Line regulation I _{OUT} vs. V _{DD}	%/dV _{DD}	5V < V _{DD} < 15V, V _{OUT} >1 V, R _{ADJ} =4.8K	-	-	±1	%/V
Load regulation I _{OUT} vs. V _{OUT}	%/dV _{OUT}	1V < V _{OUT} < 4V, I _{OUT} =20mA, R _{ADJ} =4.8K	-	-	±1	%/V
Thermal shutdown	Τ _Η	Junction Temperature	-	160	-	°C
	TL		-	110	-	°C

* Skew=(I_{OUT}-I_{AVG})/I_{AVG}, where I_{AVG}=(I_{max}+ I_{min})/2

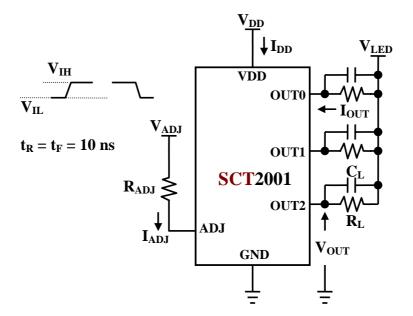
Test Circuit for Electrical Characteristics



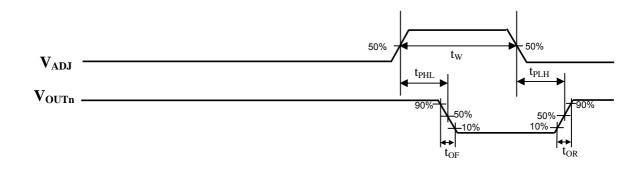
Characteristic		Symbol	Conditions	Min.	Тур.	Max.	Unit
Propagation delay time ("L" to "H")	$V_{ADJ} - V_{OUTn}$	t _{PLH}	V _{LED} = 5V	-	200	400	ns
Propagation delay time ("H" to "L")	V _{ADJ} - V _{OUTn}	t _{PHL}	$V_{IH} = 5V$ $V_{IL} = GND$ $R_{ADJ} = 4.8K\Omega$	-	200	400	ns
Pulse width	V _{ADJ}	t _w	R _L = 180Ω	2	-	-	us
Output rise time of IOUT		t _{OR}	C _L = 10pF	-	200	400	ns
Output fall time of I _{OUT}		t _{OF}		-	200	400	ns

Switching Characteristics (V_{DD}=5-15V, T_A=25°C unless otherwise noted)

Test Circuit for Switching Characteristics

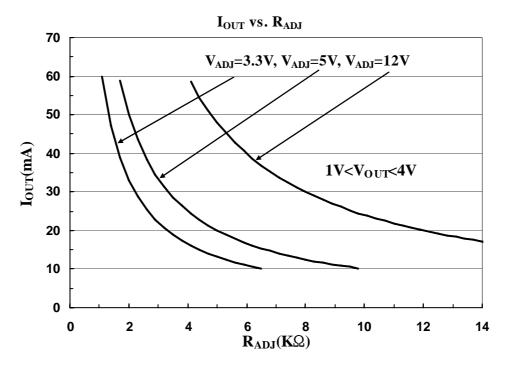


Timing Waveform



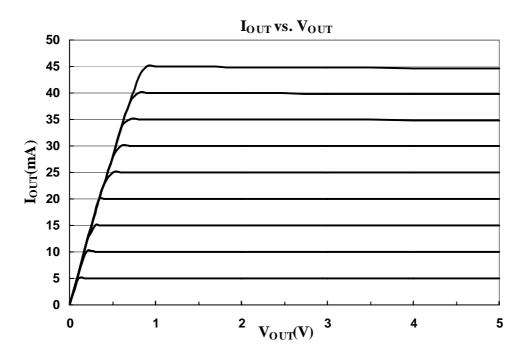
Adjusting Output Current

The output current (I_{OUT}) are set by one external resistor at pin ADJ. The relationship between I_{OUT}, resistance R_{ADJ} and reference voltage V_{ADJ} is shown as the following figure. V_{ADJ} connected to a stable reference voltage is suggested. Furthermore, I_{OUT} could be estimated by ~ I_{OUT}(A) = 20^*V_{ADJ} / (R_{ADJ} (Ω) + 200) (chip skew < $\pm 6\%$).



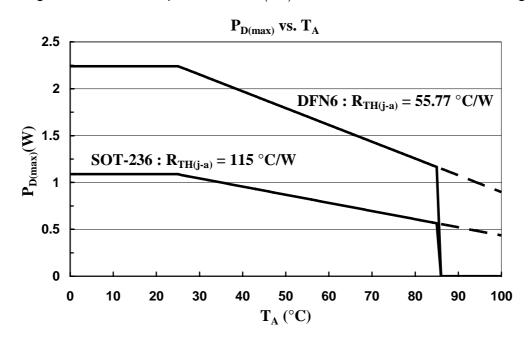
Output Characteristics

The current characteristic of output stage is flat. The output current can be kept constant regardless of the variations of LED forward voltage when $V_{OUT} > 1V$. The relationship between I_{OUT} and V_{OUT} is shown as below:



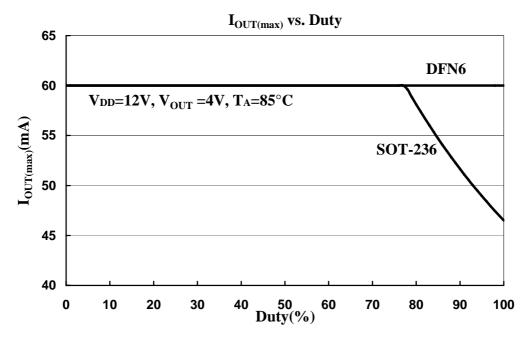
Power Dissipation

The power dissipation (P_D) of a semiconductor chip is limited by its package and ambient temperature. The maximum allowable power dissipation $P_{D(max)}$ is determined by $P_{D(max)}=(T_{J(max)} - T_A)/R_{TH(j-a)}$ where $T_{J(max)}$: maximum chip junction temperature, usually considered as 150°C, T_A : ambient temperature, $R_{TH(j-a)}$: thermal resistance of the package. The relationship between $P_{D(max)}$ and T_A is shown as the below figure:



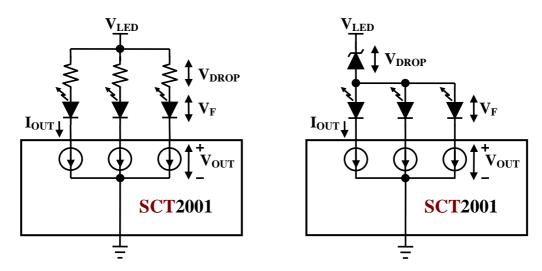
Limitation on Maximum Output Current

The maximum output current vs. duty cycle is estimated by: $I_{OUT(max)}=(((T_{J(max)}-T_A)/R_{TH(j-a)})-(V_{DD}*I_{DD}))/V_{OUT}/Duty/N$ Where $T_{J(max)}=150^{\circ}$ C, N=3(all ON)



Load Supply Voltage (VLED)

The SCT2001 can be operated very well when V_{OUT} ranging from 1V to 4V. So it is recommended to use the lowest possible supply voltage or set a voltage reducer to reduce the V_{OUT} voltage and then reduce the power dissipation of the SCT2001. Follow the diagram instructions shown below to lower down the output voltage. This can be done by adding additional resistor or zener diode, thus $V_{OUT}=V_{LED}-V_{DROP}-V_{F}$.

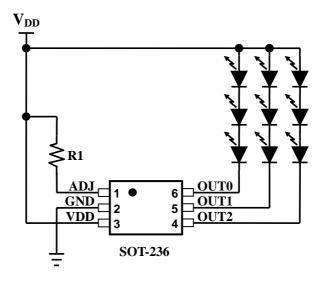


Over Temperature Shutdown

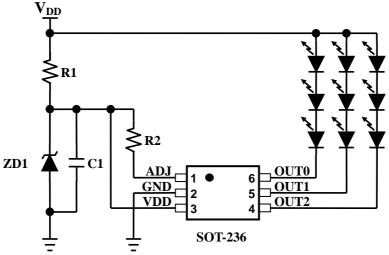
The SCT2001 contains thermal shutdown scheme to prevent damage from over heated. The internal thermal sensor turns off all outputs when the die temperature exceeds approximately +160°C. The outputs are enabled again when the die temperature drops below approximately +110°C.

Typical Application Circuits

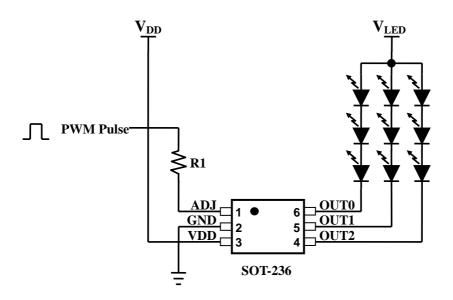
(1) Typical lighting application



(2) Typical lighting application (Zener diode as reference voltage)



(3) Lighting with dimming control

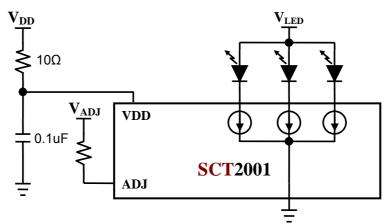


PCB Design Considerations

Use the following general guide-line when designing printed circuit boards (PCB):

Decoupling Capacitor

Place a decoupling capacitor e.g. 0.1uF between VDD and GND pins of the SCT2001. Locate the capacitor as close to the SCT2001 as possible. The necessary capacitance depends on the LED load current and dimming frequency.



External Resistor (R_{ADJ})

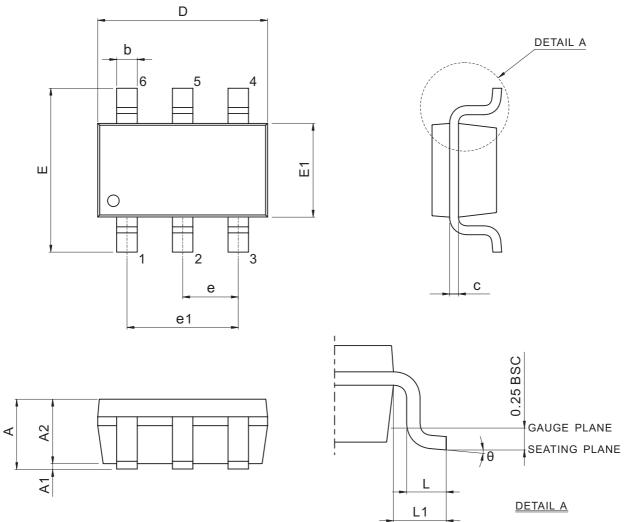
Locate the external resistor as close to the ADJ pin in as possible to avoid the noise influence.

Power and Ground

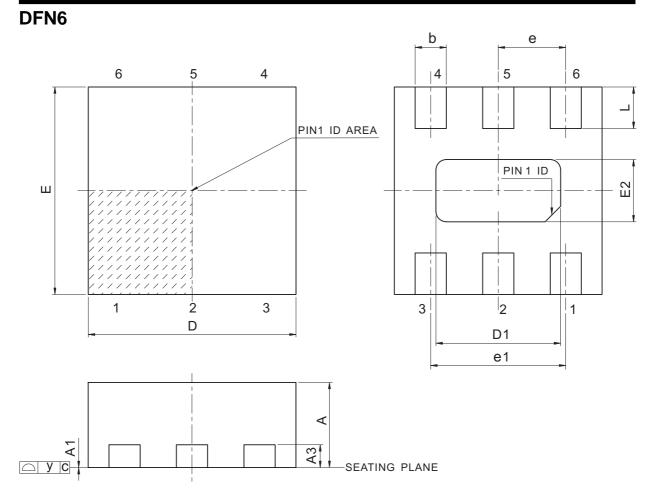
Maximizing the width and minimizing the length of V_{DD} and GND trace improve efficiency and ground bouncing by effect of reducing both power and ground parasitic resistance and inductance. A small value of resistor e.g. 10Ω series in power input of the SCT2001 in conjunction with decoupling capacitor shunting the ICs is recommended. Separating and feeding the LED power from another stable supply terminal V_{LED} is strongly recommended.

Package Dimension

SOT-236



Symbol	D	imension (mr	n)	D	imension (mi	il)
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.
А	-	-	1.45	-	-	57.1
A1	0.00	-	0.15	0.0	-	5.9
A2	0.90	1.15	1.30	35.4	45.3	51.2
b	0.30	-	0.50	11.8	-	19.7
С	0.08	-	0.22	3.2	-	8.7
D	2.90 BSC			114.2 BSC		
E		2.80 BSC			110.2 BSC	
E1		1.60 BSC			63.0 BSC	
е		0.95 BSC			37.4 BSC	
e1		1.90 BSC			74.8 BSC	
L	0.30	0.45	0.60	11.8	17.7	23.6
L1		0.60 REF			23.6 REF	
θ	0°	4°	8°	0°	4°	8°



Symbol	C	Dimension (mm)			Dimension (mil)		
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.	
A	0.70	0.75	0.80	27.6	29.5	31.5	
A1	0.00	0.02	0.05	0.0	0.8	2.0	
A3		0.20 REF			7.9 REF		
b	0.20	0.30	0.40	7.9	11.8	15.7	
D	1.9	2.00	2.10	74.8	78.7	82.7	
D1	0.00	1.20	1.25	0.0	47.2	49.2	
E	1.9	2.00	2.10	74.8	78.7	82.7	
E2	0.00	0.60	0.65	0.0	23.6	25.6	
е		0.65 BSC			25.6 BSC		
e1	1.30 BSC				51.2 BSC		
L		0.40 REF			15.7 REF		
у	-	-	0.08	-	-	3.2	

Revision History (check up-to-date version)

Data Sheet Version	Remark
V02_01	Descriptions added

Information provided by StarChips Technology is believed to be accurate and reliable. Application circuits shown, if any, are typical examples illustrating the operation of the devices. Starchips can not assume responsibility and any problem raising out of the use of the circuits. Starchips reserves the right to change product specification without prior notice.

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